# NSN 5962-01-218-5698

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## Body Length:

1.485 inches

#### **Body Width:**

Between 0.560 inches and 0.625 inches

#### **Body Height:**

0.217 inches

#### **Maximum Power Dissipation Rating:**

1.0 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Monolithic and ultraviolet erasable and hermetically sealed and programmable and electrostatic sensitive

#### **Inclosure Material:**

### Ceramic and glass

Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

N-type metal oxide-semiconductor logic

#### Input Circuit Pattern:

16 input

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 7.0 volts power source

#### Time Rating Per Chacteristic:

250.00 nanoseconds propagation delay time, low to high level output

#### Memory Device Type:

Rom

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

28 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

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